











LP38691, LP38693, LP38691-Q1, LP38693-Q1

SNVS321M - JANUARY 2005 - REVISED FEBRUARY 2015

LP3869x/-Q1 500-mA Low-Dropout CMOS Linear Regulators Stable With Ceramic Output Capacitors

1 Features

- Wide Input Voltage Range (2.7 V to 10 V)
- All WSON Options are Available as AEC-Q100 Grade 1
- 2% Output Accuracy (25°C)
- Low Dropout Voltage: 250 mV at 500 mA (Typical, 5 V Out)
- Precision (Trimmed) Bandgap Reference
- Ensured Specs for –40°C to 125°C
- 1-µA Off-State Quiescent Current
- Thermal Overload Protection
- Foldback Current Limiting
- Ground Pin Current: 55 µA (typical) at full load
- Enable Pin (LP38693)

2 Applications

- Hard Disk Drives
- Notebook Computers
- Battery-Powered Devices
- Portable Instrumentation

3 Description

The LP3869x low-dropout CMOS linear regulators provide tight output tolerance (2% typical), extremely low dropout voltage (250 mV at 500-mA load current, $V_{OUT} = 5$ V), and excellent AC performance using ultra-low equivalent series resistance (ESR) ceramic output capacitors.

The low thermal resistance of the WSON, SOT-223, and TO-252 packages allow use of the full operating current even in high ambient temperature environments.

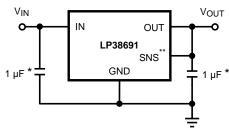
The use of a PMOS power transistor means that no DC base drive current is required to bias it, thus allowing ground pin current to remain below 100 μ A regardless of load current, input voltage, or operating temperature.

Device Information⁽¹⁾

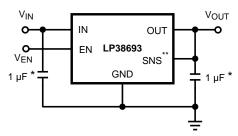
PART NUMBER	PACKAGE	BODY SIZE (NOM)				
LP38691	TO-252 (3)	6.58 mm × 6.10 mm				
	WSON (6)	3.00 mm × 3.00 mm				
I Doogoo	SOT-223 (5)	6.50 mm × 3.56 mm				
LP38693	WSON (6)	3.00 mm × 3.00 mm				
LP38691-Q1	WSON (6)	3.00 mm × 3.00 mm				
LP38693-Q1	WSON (6)	3.00 mm x 3.00 mm				

(1) For all available packages, see the orderable addendum at the end of the datasheet.

4 Typical Application Circuits



- * Minimum value required for stability
- ** WSON package devices only



- * Minimum value required for stability
- ** WSON package devices only



T -	I _ I	-	- £	^ -	nte	4
12	n	10	ΔT	. ^	nto	ntc
ıa	v		OI.	\mathbf{c}	IILE	IILO

2 Applications 1 8.4 Device Functional Modes 1 3 Description 1 9 Application and Implementation 1 4 Typical Application Circuits 1 9.1 Application Information 1 5 Revision History 2 9.2 Typical Application 1 6 Pin Configuration and Functions 3 10 Power Supply Recommendations 1 7 Specifications 4 11.1 Layout Guidelines 1 7.1 Absolute Maximum Ratings 4 11.1 Layout Guidelines 1 7.2 ESD Ratings: LP38691 and LP38693 4 11.2 Layout Example 2 7.3 ESD Ratings: LP38691-Q1 and LP38693-Q1 4 12.2 Device and Documentation Support 2 7.5 Thermal Information 5 12.1 Documentation Support 2 7.6 Electrical Characteristics 5 12.3 Trademarks 2 7.7 Typical Characteristics 7 12.4 Electrostatic Discharge Caution 2 8 Detailed Description 11 11 3 4 8.1 Overview 11 11 4 5 6 8.2 Functional Block Diagrams 11 11 11 12	1	Features 1		8.3 Feature Description	13
3 Description 1 9 Application and Implementation 1 4 Typical Application Circuits 1 9.1 Application Information 1 5 Revision History 2 9.2 Typical Application 1 6 Pin Configuration and Functions 3 10 Power Supply Recommendations 1 7 Specifications 4 11 Layout 1 7.1 Absolute Maximum Ratings 4 11.1 Layout Guidelines 1 7.2 ESD Ratings: LP38691 and LP38693 4 11.2 Layout Example 2 7.3 ESD Ratings: LP38691-Q1 and LP38693-Q1 4 12 Device and Documentation Support 2 7.4 Recommended Operating Conditions 4 12.1 Documentation Support 2 7.5 Thermal Information 5 12.2 Related Links 2 7.6 Electrical Characteristics 5 12.3 Trademarks 2 7.7 Typical Characteristics 7 12.4 Electrostatic Discharge Caution 2 8 Detailed Description 11 3 Mechanical, Packaging, and Orderable 1	•				
4 Typical Application Circuits 1 9.1 Application Information 1 5 Revision History 2 9.2 Typical Application 1 6 Pin Configuration and Functions 3 10 Power Supply Recommendations 1 7 Specifications 4 11 Layout 1 7.1 Absolute Maximum Ratings 4 11.1 Layout Guidelines 1 7.2 ESD Ratings: LP38691 and LP38693 4 11.2 Layout Example 2 7.3 ESD Ratings: LP38691-Q1 and LP38693-Q1 4 12 Device and Documentation Support 2 7.4 Recommended Operating Conditions 4 12.1 Documentation Support 2 7.5 Thermal Information 5 12.2 Related Links 2 7.6 Electrical Characteristics 5 12.3 Trademarks 2 7.7 Typical Characteristics 7 12.4 Electrostatic Discharge Caution 2 8 Detailed Description 11 3 Mechanical, Packaging, and Orderable 12 Mechanical 12 Packaging 12 Packaging 12 Packaging			9		
5 Revision History 2 9.2 Typical Application 1 6 Pin Configuration and Functions 3 10 Power Supply Recommendations 1 7 Specifications 4 11 Layout 1 7.1 Absolute Maximum Ratings 4 11.1 Layout Guidelines 1 7.2 ESD Ratings: LP38691 and LP38693 4 11.2 Layout Example 2 7.3 ESD Ratings: LP38691-Q1 and LP38693-Q1 4 12.2 Device and Documentation Support 2 7.4 Recommended Operating Conditions 4 12.1 Documentation Support 2 7.5 Thermal Information 5 12.2 Related Links 2 7.6 Electrical Characteristics 5 12.3 Trademarks 2 7.7 Typical Characteristics 7 12.4 Electrostatic Discharge Caution 2 8 Detailed Description 11 12.5 Glossary 2 8.1 Overview 11 13 Mechanical, Packaging, and Orderable 12 Provided 12 Packaging 12 Packaging 13 In the provided of the	4	•		9.1 Application Information	14
6 Pin Configuration and Functions 3 10 Power Supply Recommendations 1 7 Specifications 4 11 Layout 1 7.1 Absolute Maximum Ratings 4 11.1 Layout Guidelines 1 7.2 ESD Ratings: LP38691 and LP38693 4 11.2 Layout Example 2 7.3 ESD Ratings: LP38691-Q1 and LP38693-Q1 4 12 Device and Documentation Support 2 7.4 Recommended Operating Conditions 4 12.1 Documentation Support 2 7.5 Thermal Information 5 12.2 Related Links 2 7.6 Electrical Characteristics 5 12.3 Trademarks 2 7.7 Typical Characteristics 7 12.4 Electrostatic Discharge Caution 2 8 Detailed Description 11 3 Mechanical, Packaging, and Orderable 18 Mechanical 12 Power Supply Recommendations 1 19 Detailed Description 11 11 Power Supply Recommendations 10 Device and Documentation Support 2 12.1 Documentation Support 2 12.2 Related Links 2 12.3 Trademarks 2 12.5 Glossary 2 12.5 Glossary	-	••		9.2 Typical Application	14
7 Specifications 4 7.1 Absolute Maximum Ratings 4 7.2 ESD Ratings: LP38691 and LP38693 4 7.3 ESD Ratings: LP38691-Q1 and LP38693-Q1 4 7.4 Recommended Operating Conditions 4 7.5 Thermal Information 5 7.6 Electrical Characteristics 5 7.7 Typical Characteristics 5 7.7 Typical Characteristics 7 8 Detailed Description 11 8.1 Overview 11 12 Layout Example 2 12.1 Documentation Support 2 12.2 Related Links 2 12.3 Trademarks 2 12.4 Electrostatic Discharge Caution 2 12.5 Glossary 2 12.6 Solosary 2 12.7 Mechanical, Packaging, and Orderable 2 12 Mechanical 2	_	•	10	Power Supply Recommendations	19
7.1 Absolute Maximum Ratings 4 7.2 ESD Ratings: LP38691 and LP38693 4 7.3 ESD Ratings: LP38691-Q1 and LP38693-Q1 4 7.4 Recommended Operating Conditions 4 7.5 Thermal Information 5 7.6 Electrical Characteristics 5 7.7 Typical Characteristics 7 8 Detailed Description 11 8.1 Overview 11 11.1 Layout Guidelines 1 12.1 Documentation Support 2 12.2 Related Links 2 12.3 Trademarks 2 12.4 Electrostatic Discharge Caution 2 12.5 Glossary 12 12 Mechanical, Packaging, and Orderable 12 Mechanical 12 Mechanical 12 Mechanical 12 Mechanical	-	_	11	Layout	19
7.2 ESD Ratings: LP38691 and LP38693	•			11.1 Layout Guidelines	19
7.3 ESD Ratings: LP38691-Q1 and LP38693-Q1 4 7.4 Recommended Operating Conditions 4 7.5 Thermal Information 5 7.6 Electrical Characteristics 5 7.7 Typical Characteristics 7 8 Detailed Description 11 8.1 Overview 11 8.1 Overview 12.0 Device and Documentation Support 2 12.1 Documentation Support 2 12.2 Related Links 2 12.3 Trademarks 2 12.4 Electrostatic Discharge Caution 2 12.5 Glossary 2 Mechanical, Packaging, and Orderable 1 12.6 Information 2		3		11.2 Layout Example	20
7.4 Recommended Operating Conditions 4 12.1 Documentation Support 2 7.5 Thermal Information 5 12.2 Related Links 2 7.6 Electrical Characteristics 5 12.3 Trademarks 2 7.7 Typical Characteristics 7 12.4 Electrostatic Discharge Caution 2 8 Detailed Description 11 12.5 Glossary 2 8.1 Overview 11 13 Mechanical, Packaging, and Orderable Information 2		· ·	12		
7.5 Thermal Information 5 12.2 Related Links 2 7.6 Electrical Characteristics 5 12.3 Trademarks 2 7.7 Typical Characteristics 7 12.4 Electrostatic Discharge Caution 2 8 Detailed Description 11 12.5 Glossary 2 8.1 Overview 11 13 Mechanical, Packaging, and Orderable Information 2				12.1 Documentation Support	21
7.6 Electrical Characteristics 5 12.3 Trademarks 2 7.7 Typical Characteristics 7 12.4 Electrostatic Discharge Caution 2 8 Detailed Description 11 12.5 Glossary 2 8.1 Overview 11 13 Mechanical, Packaging, and Orderable Information 2		,		12.2 Related Links	21
7.7 Typical Characteristics 7 12.4 Electrostatic Discharge Caution 2 12.5 Glossary 2 12.5 Glossary 2 13 Mechanical, Packaging, and Orderable Information 2 14 Information 2 15 I				12.3 Trademarks	21
8 Detailed Description 11 12.5 Glossary 2 8.1 Overview 11 Mechanical, Packaging, and Orderable				12.4 Electrostatic Discharge Caution	21
8.1 Overview	R	**		9	
8.2 Functional Block Diagrams	•	-	13	Mechanical, Packaging, and Orderable	24
		8.2 Functional Block Diagrams 11		miormation	21

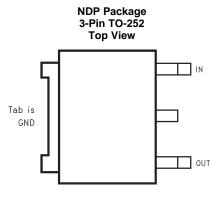
5 Revision History

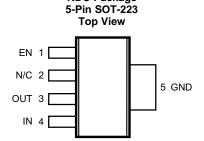
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

С	hanges from Revision L (December 2014) to Revision M	Page
•	Changed wording of <i>Description</i> and added one item to <i>Features</i> ; update Vin, Vout and Ven pin names to IN, OUT, and EN in text and graphics	
•	Changed "PFM" to 'TO-252"	4
•	Changed Handling Ratings to ESD Ratings format	4
С	hanges from Revision K (April 2013) to Revision L	Page
•	Added Handling Rating table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section; update thermal values	1
С	hanges from Revision J (April 2013) to Revision K	Page
•	Changed layout of National Data Sheet to TI format	18
_		



6 Pin Configuration and Functions

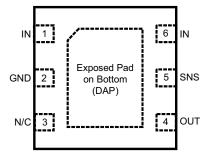




NDC Package

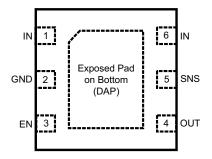
NC - No internal connection

NGG Package 6-Pin WSON With Exposed Thermal Pad LP38691SD Top View



NC - No internal connection

NGG Package 6-Pin WSON With Exposed Thermal Pad LP38693SD Top View





Pin Functions

		PIN				
NAME	TO- 252	ws	ON	SOT- 223	I/O	DESCRIPTION
DAP	_	√	√	_	_	WSON Only - The DAP (Exposed Pad) functions as a thermal connection when soldered to a copper plane. See WSON Mounting section for more information.
EN	_	1	3	1	1	The EN pin allows the part to be turned ON and OFF by pulling this pin high or low.
GND	TAB	2	2	5	_	Circuit ground for the regulator. For the TO-252 and SOT-223 packages this is thermally connected to the die and functions as a heat sink when the soldered down to a large copper plane.
IN	3	1, 6	1, 6	4	1	This is the input supply voltage to the regulator. For WSON devices, both IN pins must be tied together for full current operation (250 mA maximum per pin).
OUT	1	4	4	3	0	Regulated output voltage
SNS	_	5	5	_	I	WSON Only - Output SNS pin allows remote sensing at the load which will eliminate the error in output voltage due to voltage drops caused by the resistance in the traces between the regulator and the load. This pin must be tied to OUT.

7 Specifications

7.1 Absolute Maximum Ratings⁽¹⁾⁽²⁾

	MIN	MAX	UNIT
Lead temp. (Soldering, 5 seconds)		260	°C
Power dissipation ⁽³⁾	Internally Limited		V
V(max) All pins (with respect to GND)	-0.3	12	V
I _{OUT} ⁽⁴⁾	Internally Limited		V
Junction temperature	-40	150	°C
Storage temperature, T _{stg}	-65	150	

- (1) Absolute maximum ratings indicate limits beyond which damage to the component may occur. Operating ratings indicate conditions for which the device is intended to be functional, but do not ensure specific performance limits. For ensured specifications, see *Electrical Characteristics*. Specifications do not apply when operating the device outside of its rated operating conditions.
- (2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.
- (3) At elevated temperatures, device power dissipation must be derated based on package thermal resistance and heatsink values (if a heatsink is used). When using the WSON package, refer to AN-1187 Leadless Leadframe Package (LLP), SNOA401, and the WSON Mounting section in this datasheet. If power dissipation causes the junction temperature to exceed specified limits, the device will go into thermal shutdown.
- (4) If used in a dual-supply system where the regulator load is returned to a negative supply, the output pin must be diode clamped to ground.

7.2 ESD Ratings: LP38691 and LP38693

			VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)	±2000	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

7.3 ESD Ratings: LP38691-Q1 and LP38693-Q1

			VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human-body model (HBM), per AEC Q100-002 ⁽¹⁾	±2000	V

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

7.4 Recommended Operating Conditions

	MIN	NOM MAX	UNIT
V _{IN} supply voltage	2.7	10	٧
Operating junction temperature	-40	125	°C

Submit Documentation Feedback



7.5 Thermal Information

		LP38691	LP38693	LP3869x	
	THERMAL METRIC ⁽¹⁾	TO-252	WSON	SOT-223	UNIT
		3 PINS	6 PINS	5 PINS	
$R_{\theta JA}^{(2)}$	Junction-to-ambient thermal resistance	50.5	50.6	68.5	
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	52.6	44.4	52.2	
$R_{\theta JB}$	Junction-to-board thermal resistance	29.7	24.9	13.0	°C/W
ΨЈТ	Junction-to-top characterization parameter	4.8	0.4	5.5	C/VV
ΨЈВ	Junction-to-board characterization parameter	29.3	25.1	12.8	
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	1.5	5.4	n/a	

⁽¹⁾ For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

7.6 Electrical Characteristics

Unless otherwise specified, limits apply for $T_J = 25^{\circ}C$, $V_{IN} = V_{OUT} + 1$ V, $C_{IN} = C_{OUT} = 10$ μ F, $I_{LOAD} = 10$ mA. Minimum and maximum limits are specified through testing, statistical correlation, or design.

	PARAMETER	TEST CON	IDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
				-2		2	
Vo	Output voltage tolerance	100 μ A < I _L < 0.5 A V _O + 1 V ≤ V _{IN} ≤ 10 V Full operating temperature ra	ange	-4		4	%V _{OUT}
$\Delta V_{O}/\Delta V_{IN}$	Output voltage line regulation (2)	$V_{O} + 0.5 \text{ V} \le V_{IN} \le 10 \text{ V}$ $I_{L} = 25 \text{ mA}$			0.03		
		$V_O + 0.5 \text{ V} \le V_{IN} \le 10 \text{ V}$ $I_L = 25 \text{ mA}$ Full operating temperature ra	inge			0.1	%/V
$\Delta V_O/\Delta I_L$	Output voltage load regulation (3)	1 mA < I _L < 0.5 A V _{IN} = V _O + 1 V			1.8		
		1 mA < I_L < 0.5 A $V_{IN} = V_O + 1 V$ Full operating temperature ra	inge			5	%/A
		(V _O = 2.5 V)	I _L = 0.1 A		80		
		(VO = 2.5 V)	I _L = 0.5 A		430		
		$(V_0 = 2.5 \text{ V})$	I _L = 0.1 A			145	
		Full operating temperature range	I _L = 0.5 A			_	
		0/ 2210	I _L = 0.1 A		65		
	- (4)	$(V_0 = 3.3 \text{ V})$	I _L = 0.5 A		330		
$V_{IN} - V_{OUT}$	Dropout voltage (4)	$(V_0 = 3.3 \text{ V})$	I _L = 0.1 A			110	mV
		Full operating temperature range	I _L = 0.5 A).5 A	550		
		(\(- \ \ \)	$I_L = 0.1 A$		45		
		(V _O = 5 V)	$I_L = 0.5 A$		250		
		$(V_O = 5 V)$	$I_L = 0.1 A$			100	
		Full operating temperature range	I _L = 0.5 A			450	

⁽²⁾ Junction-to-ambient thermal resistance, High-K.

⁽¹⁾ Typical numbers represent the most likely parametric norm for 25°C operation.

⁽²⁾ Output voltage line regulation is defined as the change in output voltage from nominal value resulting from a change in input voltage.

⁽³⁾ Output voltage load regulation is defined as the change in output voltage from nominal value as the load current increases from 1 mA to full load.

⁽⁴⁾ Dropout voltage is defined as the minimum input to output differential required to maintain the output within 100 mV of nominal value.



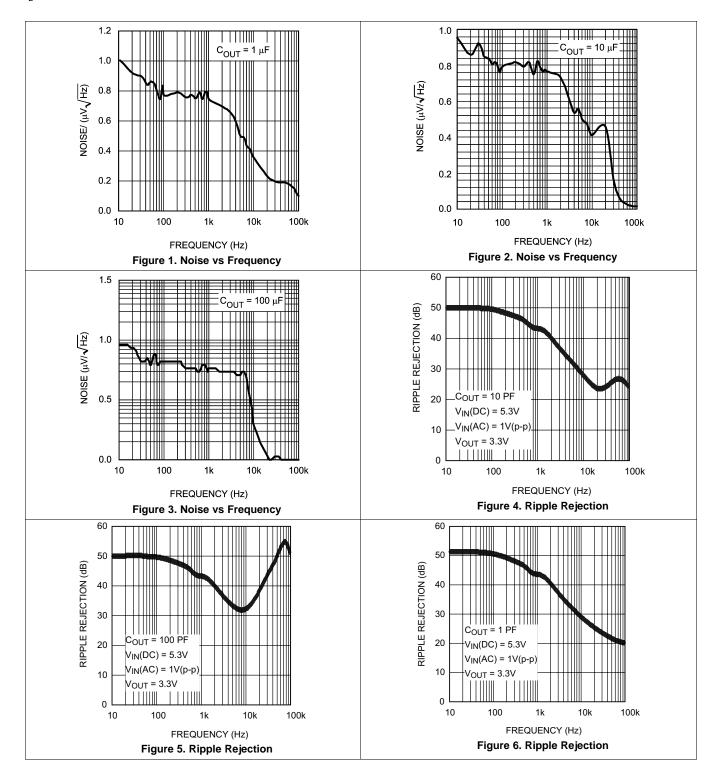
Electrical Characteristics (continued)

Unless otherwise specified, limits apply for $T_J = 25^{\circ}C$, $V_{IN} = V_{OUT} + 1$ V, $C_{IN} = C_{OUT} = 10$ μ F, $I_{LOAD} = 10$ mA. Minimum and maximum limits are specified through testing, statistical correlation, or design.

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
IQ	Quiescent current	V _{IN} ≤ 10 V, I _L =100 μA - 0.5 A		55		
		$V_{IN} \le 10 \text{ V}, I_L = 100 \mu\text{A} - 0.5 \text{ A}$ Full operating temperature range			100	
		V _{EN} ≤ 0.4 V, (LP38693 Only)		0.001	1	μA
I _L (MIN)	Minimum load current	$V_{IN} - V_O \le 4 V$ Full operating temperature range			100	
1	Foldback current limit	$V_{IN} - V_O > 5 V$		350		mA
I _{FB}	FOIDDACK CUITEIII IIIIIII	$V_{IN} - V_O < 4 V$		850		IIIA
PSRR	Ripple rejection	$V_{IN} = V_O + 2 V(DC)$, with 1 V(p-p) / 120-Hz Ripple		55		dB
T _{SD}	Thermal shutdown activation (junction temp)			160		°C
T _{SD} (HYST)	Thermal shutdown hysteresis (junction temp)			10		
e _n	Output noise	BW = 10 Hz to 10 kHz V _O = 3.3 V		0.7		μV/√ Hz
V _O (LEAK)	Output leakage current	$V_O = V_O(NOM) + 1 V at 10 V_{IN}$		0.5	12	μΑ
		Output = OFF Full operating temperature range			0.4	
W	Enable voltage (LP38693	Output = ON, V _{IN} = 4 V Full operating temperature range	1.8			.,
V _{EN}	Only)	Output = ON, V _{IN} = 6 V Full operating temperature range	perating temperature range t = ON, V _{IN} = 10 V		V	
		Output = ON, V _{IN} = 10 V Full operating temperature range				
I _{EN}	Enable pin leakage (ILP38693 only)	V _{EN} = 0 V or 10 V, V _{IN} = 10 V	-1	0.001	1	μA

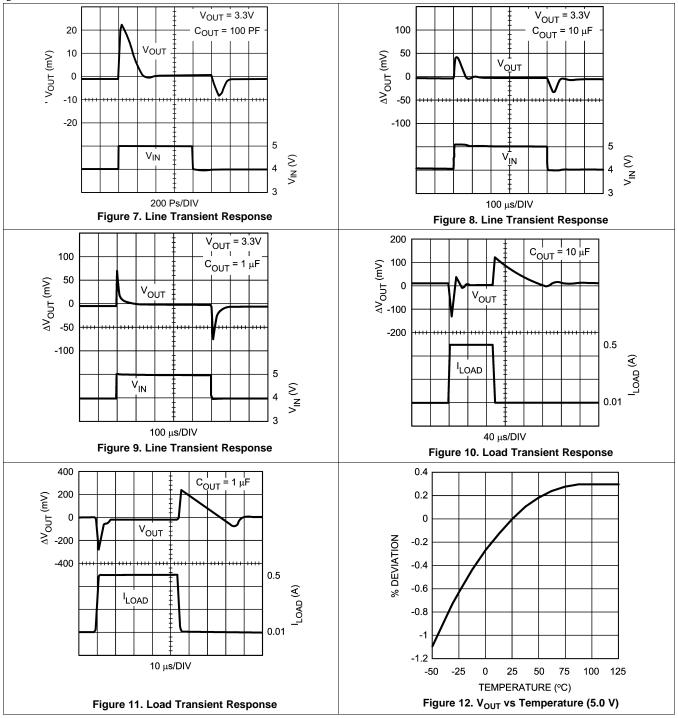


7.7 Typical Characteristics



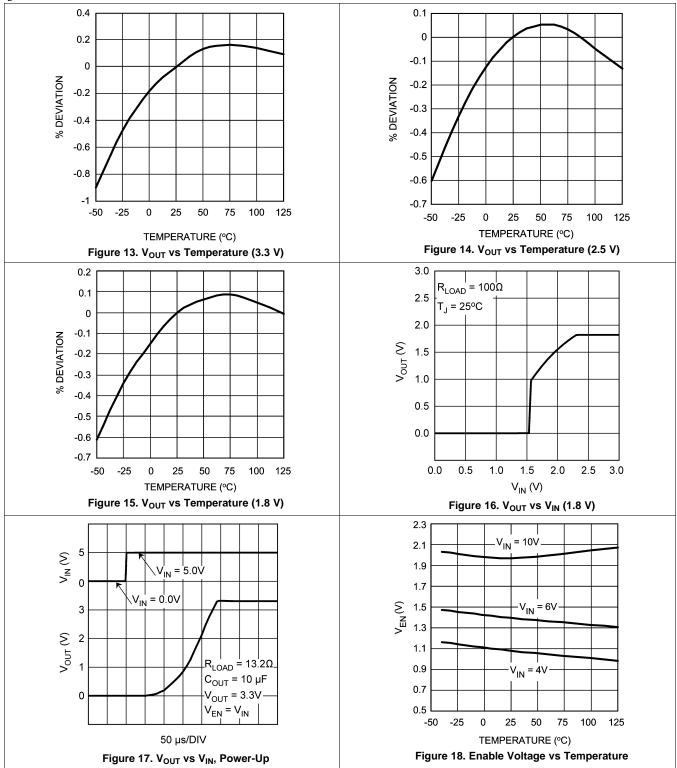


Typical Characteristics (continued)



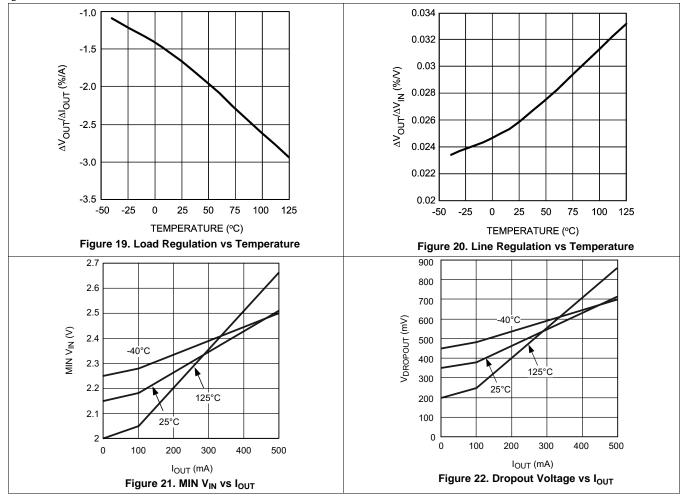


Typical Characteristics (continued)





Typical Characteristics (continued)





8 Detailed Description

8.1 Overview

The LP38691 and LP38693 are designed to meet the requirements of portable, battery-powered digital systems providing an accurate output voltage with fast start-up. When disabled via a low logic signal at the enable pin (EN), the power consumption is reduced to virtually zero (LP38693 only).

The LP38691 and LP38693 perform well with a single 1-μF input capacitor and a single 1-μF ceramic output capacitor.

8.2 Functional Block Diagrams

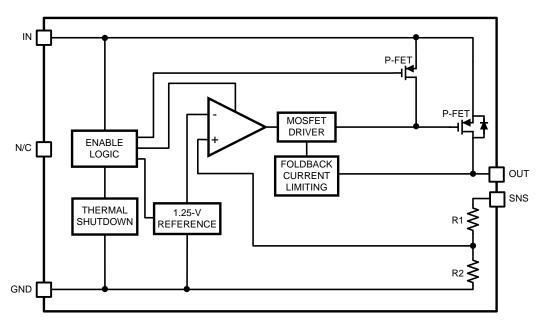


Figure 23. LP38691 Functional Diagram (WSON)

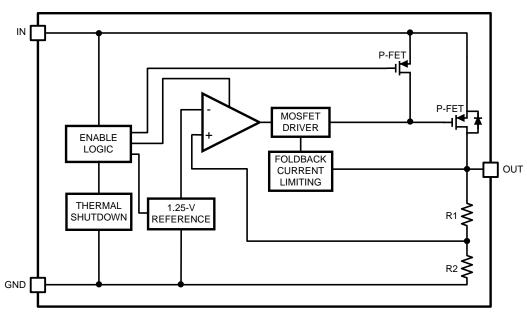


Figure 24. LP38691 Functional Diagram (TO-252)

Functional Block Diagrams (continued)

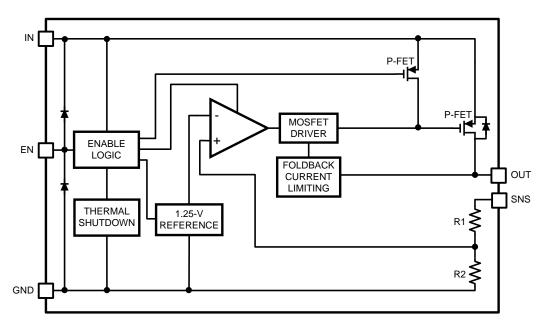


Figure 25. LP38693 Functional Diagram (WSON)

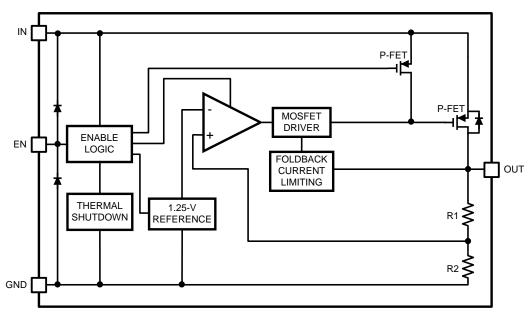


Figure 26. LP38693 Functional Diagram (SOT-223)



8.3 Feature Description

8.3.1 Enable (EN)

The LP38693 has an Enable pin (EN) which allows an external control signal to turn the regulator output On and Off. The Enable On/Off threshold has no hysteresis. The voltage signal must rise and fall cleanly, and promptly, through the ON and OFF voltage thresholds. The EN pin voltage must be higher than the $V_{\text{EN(MIN)}}$ threshold to ensure that the device is fully enabled under all operating conditions. The EN pin voltage must be lower than the $V_{\text{EN(MAX)}}$ threshold to ensure that the device is fully disabled. The EN pin has no internal pullup or pulldown to establish a default condition and, as a result, this pin must be terminated either actively or passively. If the EN pin is driven from a source that actively pulls high and low, the drive voltage should not be allowed to go below ground potential or higher than V_{IN} . If the application does not require the Enable function, the pin should be connected directly to the IN pin.

8.3.2 Thermal Overload Protection (T_{SD})

Thermal Shutdown disables the output when the junction temperature rises to approximately 160°C which allows the device to cool. When the junction temperature cools to approximately 150°C, the output circuitry enables.

Based on power dissipation, thermal resistance, and ambient temperature, the thermal protection circuit may cycle on and off. This thermal cycling limits the dissipation of the regulator and protects it from damage as a result of overheating. The Thermal Shutdown circuitry of the LP38693 has been designed to protect against temporary thermal overload conditions.

The Thermal Shutdown circuitry was not intended to replace proper heat-sinking. Continuously running the LP38693 device into thermal shutdown degrades device reliability.

8.3.3 Foldback Current Limiting

Foldback current limiting is built into the LP38691 and LP38693 devices which reduces the amount of output current the part can deliver as the output voltage is reduced. The amount of load current is dependent on the differential voltage between the IN and OUT pins. Typically, when this differential voltage exceeds 5 V, the load current will limit at about 350 mA. When the $V_{IN} - V_{OUT}$ differential is reduced below 4 V, load current is limited to about 850 mA.

8.4 Device Functional Modes

8.4.1 Enable (EN)

The EN pin voltage must be higher than the $V_{EN(MIN)}$ threshold to ensure that the device is fully enabled under all operating conditions.

8.4.2 Minimum Operating Input Voltage (VIN)

The LP38691 and LP38693 do not include any dedicated UVLO circuitry. Neither device internal circuitry is fully functional until V_{IN} is at least 2.7 V. The output voltage is not regulated until $V_{IN} \ge (V_{OUT} + V_{DO})$, or 2.7 V, whichever is higher.



9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

9.1.1 Reverse Voltage

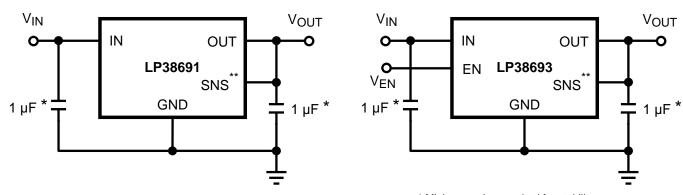
A reverse voltage condition will exist when the voltage at the output pin is higher than the voltage at the input pin. Typically this will happen when V_{IN} is abruptly taken low and C_{OUT} continues to hold a sufficient charge such that the input to output voltage becomes reversed. A less common condition is when an alternate voltage source is connected to the output.

There are two possible paths for current to flow from the OUT pin back to IN during a reverse voltage condition.

- 1. While V_{IN} is high enough to keep the control circuity alive, and the EN pin (LP38693 only) is above the $V_{EN(ON)}$ threshold, the control circuitry will attempt to regulate the output voltage. If the input voltage is less than the programmed output voltage, the control circuit will drive the gate of the pass element to the full ON condition. In this condition, reverse current will flow from the OUT to the IN pin, limited only by the $R_{DS(ON)}$ of the pass element and the output to input voltage differential. Discharging an output capacitor up to 1000 μ F in this manner will not damage the device as the current will rapidly decay. However, continuous reverse current should be avoided. When the EN pin is low, this condition will be prevented.
- 2. The internal PFET pass element has an inherent parasitic diode. During normal operation, the input voltage is higher than the output voltage and the parasitic diode is reverse biased. However, when V_{IN} is below the value where the control circuity is alive, or the EN pin is low (LP38693 only), and the output voltage is more than 500 mV (typical) above the input voltage the parasitic diode becomes forward biased and current flows from the output pin to the input pin through the diode. The current in the parasitic diode should be limited to less than 1 A continuous and 5 A peak.

If used in a dual-supply system where the regulator output load is returned to a negative supply, the output pin must be diode clamped to ground to limit the negative voltage transition. A Schottky diode is recommended for this protective clamp.

9.2 Typical Application



^{*} Minimum value required for stability.

^{**}WSON package devices only.



9.2.1 Design Requirements

Table 1. Design Parameters

DESIGN PARAMETERS	EXAMPLE VALUE
Input voltage range	2.7 V to 10 V
Output range	1.8 V
Output current	1 A
Output capacitor range	1 μF
Input and output capacitor ESR range	5 mΩ to 500 mΩ

9.2.2 Detailed Design Procedure

9.2.2.1 Power Dissipation and Device Operation

The permissible power dissipation for any package is a measure of the capability of the device to pass heat from the power source, the junctions of the IC, to the ultimate heat sink, the ambient environment. Thus, the power dissipation is dependent on the ambient temperature and the thermal resistance across the various interfaces between the die junction and ambient air.

The maximum allowable power dissipation for the device in a given package can be calculated using Equation 1:

$$P_{D-MAX} = ((T_{J-MAX} - T_A) / R_{\theta JA})$$
 (1)

The actual power being dissipated in the device can be represented by Equation 2:

$$P_{D} = (V_{IN} - V_{OUT}) \times I_{OUT}$$
 (2)

These two equations establish the relationship between the maximum power dissipation allowed due to thermal consideration, the voltage drop across the device, and the continuous current capability of the device. These two equations should be used to determine the optimum operating conditions for the device in the application.

In applications where lower power dissipation (P_D) and/or excellent package thermal resistance ($R_{\theta JA}$) is present, the maximum ambient temperature (T_{A-MAX}) may be increased.

In applications where high power dissipation and/or poor package thermal resistance is present, the maximum ambient temperature (T_{A-MAX}) may have to be derated. T_{A-MAX} is dependent on the maximum operating junction temperature ($T_{J-MAX-OP} = 125$ °C), the maximum allowable power dissipation in the device package in the application (P_{D-MAX}), and the junction-to ambient thermal resistance of the part/package in the application ($R_{\theta JA}$), as given by Equation 3:

$$T_{A-MAX} = (T_{J-MAX-OP} - (R_{\theta JA} \times P_{D-MAX}))$$
(3)

Alternately, if T_{A-MAX} can not be derated, the P_D value must be reduced. This can be accomplished by reducing V_{IN} in the ' $V_{IN} - V_{OUT}$ ' term as long as the minimum V_{IN} is met, or by reducing the I_{OUT} term, or by some combination of the two.

9.2.2.2 External Capacitors

In common with most regulators, the LP38691 and LP38693 require an external capacitors for regulator stability. The devices are specifically designed for portable applications requiring minimum board space and smallest components. These capacitors must be correctly selected for good performance.

9.2.2.3 Input Capacitor

An input capacitor is required for stability. It is recommended that a 1-µF capacitor be connected between the devices' IN pin and GND pin (this capacitance value may be increased without limit).

This capacitor must be located a distance of not more than 1 cm from the IN pin and returned to a clean analogue ground. Any good quality ceramic, tantalum, or film capacitor may be used at the input.



Important: To ensure stable operation it is essential that good PCB design practices are employed to minimize ground impedance and keep input inductance low. If these conditions cannot be met, or if long leads are used to connect the battery or other power source to the LP38691 or LP38693, then it is recommended that the input capacitor is increased. Also, tantalum capacitors can suffer catastrophic failures due to surge current when connected to a low-impedance source of power (like a battery or a very large capacitor). If a tantalum capacitor is used at the input, it must be ensured by the manufacturer to have a surge current rating sufficient for the application.

There are no requirements for the equivalent series resistance (ESR) on the input capacitor, but tolerance and temperature coefficient must be considered when selecting the capacitor to ensure the capacitance will remain approximately 1 µF over the entire operating temperature range.

9.2.2.4 Output Capacitor

The LP3869x is designed specifically to work with very small ceramic output capacitors. A 1- μ F ceramic capacitor (temperature types Z5U, Y5V or X7R/X5R) with ESR between 5 m Ω to 500 m Ω , is suitable in the LP3869x application circuit.

For this device the output capacitor should be connected between the OUT pin and GND pin.

It is also possible to use tantalum or film capacitors at the device output, but these are not as attractive for reasons of size and cost.

The output capacitor must meet the requirement for the minimum value of capacitance and also have an ESR value that is within the range 5 m Ω to 500 m Ω for stability.

9.2.2.5 No-Load Stability

The LP3869x will remain stable and in regulation with no external load. This is an important consideration in some circuits, for example CMOS RAM keep-alive applications.

9.2.2.6 Capacitor Characteristics

The LP3869x is designed to work with ceramic capacitors on the output to take advantage of the benefits they offer. For capacitance values in the range of 0.47 μ F to 4.7 μ F, ceramic capacitors are the smallest, least expensive and have the lowest ESR values, thus making them best for eliminating high frequency noise. The ESR of a typical 1- μ F ceramic capacitor is in the range of 20 m Ω to 40 m Ω , which easily meets the ESR requirement for stability for the LP3869x.

For both input and output capacitors, careful interpretation of the capacitor specification is required to ensure correct device operation. The capacitor value can change greatly, depending on the operating conditions and capacitor type.

In particular, the output capacitor selection should take account of all the capacitor parameters, to ensure that the specification is met within the application. The capacitance can vary with DC bias conditions as well as temperature and frequency of operation. Capacitor values will also show some decrease over time due to aging. The capacitor parameters are also dependent on the particular case size, with smaller sizes giving poorer performance figures in general. As an example, Figure 27 shows a typical graph comparing different capacitor case sizes in a Capacitance vs. DC Bias plot. As shown in the graph, increasing the DC Bias condition can result in the capacitance value falling below the minimum value given in the recommended capacitor specifications table (0.7 μ F in this case). Note that the graph shows the capacitance out of specification for the 0402 case size capacitor at higher bias voltages. It is therefore recommended that the capacitor manufacturers' specifications for the nominal value capacitor are consulted for all conditions, as some capacitor sizes (for example, 0402) may not be suitable in the actual application.

6 Submit Documentation Feedback

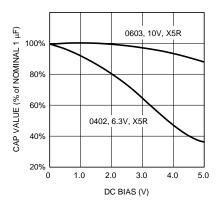


Figure 27. Typical Variation In Capacitance vs DC Bias

The value of the ceramic capacitor can vary with temperature. The capacitor type X7R, which operates over a temperature range of -55° C to 125° C, will only vary the capacitance to within $\pm 15\%$. The capacitor type X5R has a similar tolerance over a reduced temperature range of -55° C to 85° C. Many large value ceramic capacitors, larger than 1 μ F, are manufactured with Z5U or Y5V temperature characteristics. Their capacitance can drop by more than 50% as the temperature varies from 25°C to 85° C. Therefore, X7R and X5R types are recommended over Z5U and Y5V in applications where the ambient temperature will change significantly above or below 25°C.

Tantalum capacitors are less desirable than ceramic for use as output capacitors because they are more costly when comparing equivalent capacitance and voltage ratings in the 0.47-µF to 4.7-µF range.

Another important consideration is that tantalum capacitors have higher ESR values than equivalent size ceramics. This means that while it may be possible to find a tantalum capacitor with an ESR value within the stable range, it would have to be larger in capacitance (which means bigger and more costly) than a ceramic capacitor with the same ESR value. It should also be noted that the ESR of a typical tantalum will increase about 2:1 as the temperature goes from 25°C down to -40°C, so some guard band must be allowed.

9.2.2.7 RFI/EMI Susceptibility

Radio frequency interference (RFI) and electromagnetic interference (EMI) can degrade any integrated circuit's performance because of the small dimensions of the geometries inside the device. In applications where circuit sources are present which generate signals with significant high frequency energy content (> 1 MHz), care must be taken to ensure that this does not affect the device regulator.

If RFI/EMI noise is present on the input side of the regulator (such as applications where the input source comes from the output of a switching regulator), good ceramic bypass capacitors must be used at the input pin of the device.

If a load is connected to the device output which switches at high speed (such as a clock), the high-frequency current pulses required by the load must be supplied by the capacitors on the IC output. Because the bandwidth of the regulator loop is less than 100 kHz, the control circuitry cannot respond to load changes above that frequency. This means the effective output impedance of the device at frequencies above 100 kHz is determined only by the output capacitors.

In applications where the load is switching at high speed, the output of the IC may need RF isolation from the load. It is recommended that some inductance be placed between the output capacitor and the load, and good RF bypass capacitors be placed directly across the load.

PCB layout is also critical in high noise environments, because RFI/EMI is easily radiated directly into PC traces. Noisy circuitry should be isolated from *clean* circuits where possible, and grounded through a separate path. At MHz frequencies, ground planes begin to look inductive and RFI/ EMI can cause ground bounce across the ground plane. In multi-layer PCB applications, care should be taken in layout so that noisy power and ground planes do not radiate directly into adjacent layers which carry analog power and ground.



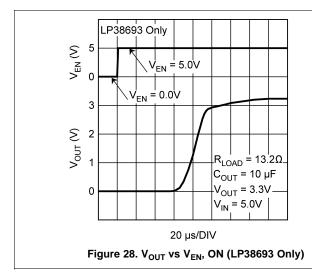
9.2.2.8 Output Noise

Noise is specified in two ways: Spot Noise or Output Noise Density is the RMS sum of all noise sources, measured at the regulator output, at a specific frequency (measured with a 1-Hz bandwidth). This type of noise is usually plotted on a curve as a function of frequency. Total Output Noise or Broad-Band Noise is the RMS sum of spot noise over a specified bandwidth, usually several decades of frequencies.

Attention should be paid to the units of measurement. Spot noise is measured in units $\mu V \sqrt{Hz}$ or $nV \sqrt{Hz}$, and total output noise is measured in $\mu V_{(rms)}$.

The primary source of noise in low-dropout regulators is the internal reference. Noise can be reduced in two ways: by increasing the transistor area or by increasing the current drawn by the internal reference. Increasing the area will decrease the chance of fitting the die into a smaller package. Increasing the current drawn by the internal reference increases the total supply current (GND pin current).

9.2.3 Application Curves



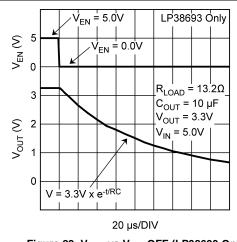


Figure 29. V_{OUT} vs V_{EN} , OFF (LP38693 Only)



10 Power Supply Recommendations

The LP38691 and LP38693 are designed to operate from an input supply voltage range of 2.7 V to 10 V. The input supply should be well regulated and free of spurious noise. To ensure that the device output voltage is well regulated, input supply should be at least $V_{OUT} + 0.5 V$, or 2.7 V, whichever is higher. A minimum capacitor value of 1- μ F is required to be within 1 cm of the IN pin.

11 Layout

11.1 Layout Guidelines

The dynamic performance of the LP38691 or LP38693 is dependent on the layout of the PCB. PCB layout practices that are adequate for typical LDOs may degrade the load regulation, PSRR, noise, or transient performance of the LP38691 or LP38693.

Best performance is achieved by placing C_{IN} and C_{OUT} on the same side of the PCB as the LP38691 or LP38693, and as close as is practical to the package. The ground connections for C_{IN} and C_{OUT} should be back to the LP38691 or LP38693 GND pin using as wide, and as short, a copper trace as is practical.

Connections using long trace lengths, narrow trace widths, and/or connections through vias should be avoided. These will add parasitic inductances and resistance that results in inferior performance especially during transient conditions.

A Ground Plane, either on the opposite side of a two-layer PCB, or embedded in a multi-layer PCB, is strongly recommended. This Ground Plane serves two purposes:

- Provides a circuit reference plane to assure accuracy.
- Provides a thermal plane to remove heat from the LP38691 or LP38693 WSON package through thermal vias under the package DAP.

11.1.1 WSON Mounting

The NGG0006A (No Pullback) 6-Lead WSON package requires specific mounting techniques which are detailed in the TI *AN-1187 Application Report* SNOA401. Referring to the section *PCB Design Recommendations*, it should be noted that the pad style which should be used with the WSON package is the NSMD (non-solder mask defined) type. Additionally, it is recommended the PCB terminal pads to be 0.2 mm longer than the package pads to create a solder fillet to improve reliability and inspection.

The input current is split between two IN pins, 1 and 6. The two IN pins must be connected together to ensure that the device can meet all specifications at the rated current.

The thermal dissipation of the WSON package is directly related to the printed circuit board construction and the amount of additional copper area connected to the DAP.

The DAP (exposed pad) on the bottom of the WSON package is connected to the die substrate with a conductive die attach adhesive. The DAP has no direct electrical (wire) connection to any of the pins. There is a parasitic PN junction between the die substrate and the device ground. As such, it is strongly recommend that the DAP be connected directly to the ground at device lead 2 (that is, GND). Alternately, but not recommended, the DAP may be left floating (that is, no electrical connection). The DAP must not be connected to any potential other than ground.



11.2 Layout Example

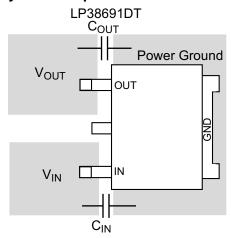


Figure 30. TO-252 Package

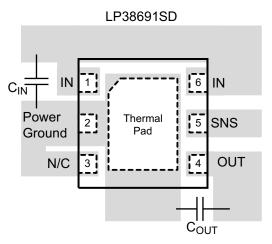


Figure 31. WSON LP38691 Layout

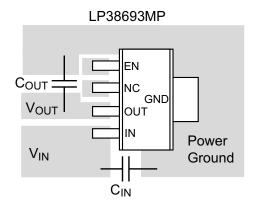


Figure 32. SOT-223 Layout

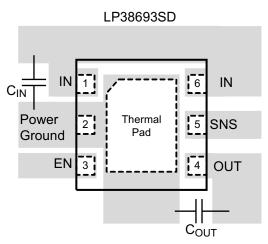


Figure 33. WSON LP38693 Layout



12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Related Documentation

For related documentation see the following:

Texas Instruments AN-1187 Leadless Leadframe Package (LLP) (SNOA401).

12.2 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 2. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
LP38691	Click here	Click here	Click here	Click here	Click here
LP38693	Click here	Click here	Click here	Click here	Click here
LP38691-Q1	Click here	Click here	Click here	Click here	Click here
LP38693-Q1	Click here	Click here	Click here	Click here	Click here

12.3 Trademarks

All trademarks are the property of their respective owners.

12.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.





28-Jan-2015

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
LP38691DT-1.8	NRND	TO-252	NDP	3	75	TBD	Call TI	Call TI	-40 to 125	LP38691 DT-1.8	
LP38691DT-1.8/NOPB	ACTIVE	TO-252	NDP	3	75	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	LP38691 DT-1.8	Samples
LP38691DT-2.5	NRND	TO-252	NDP	3	75	TBD	Call TI	Call TI	-40 to 125	LP38691 DT-2.5	
LP38691DT-2.5/NOPB	ACTIVE	TO-252	NDP	3	75	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	LP38691 DT-2.5	Samples
LP38691DT-3.3	NRND	TO-252	NDP	3	75	TBD	Call TI	Call TI	-40 to 125	LP38691 DT-3.3	
LP38691DT-3.3/NOPB	ACTIVE	TO-252	NDP	3	75	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	LP38691 DT-3.3	Samples
LP38691DT-5.0/NOPB	ACTIVE	TO-252	NDP	3	75	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	LP38691 DT-5.0	Samples
LP38691DTX-1.8/NOPB	ACTIVE	TO-252	NDP	3	2500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	LP38691 DT-1.8	Samples
LP38691DTX-2.5/NOPB	ACTIVE	TO-252	NDP	3	2500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	LP38691 DT-2.5	Samples
LP38691DTX-3.3	NRND	TO-252	NDP	3	2500	TBD	Call TI	Call TI	-40 to 125	LP38691 DT-3.3	
LP38691DTX-3.3/NOPB	ACTIVE	TO-252	NDP	3	2500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	LP38691 DT-3.3	Samples
LP38691DTX-5.0/NOPB	ACTIVE	TO-252	NDP	3	2500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	LP38691 DT-5.0	Samples
LP38691QSD-1.8/NOPB	ACTIVE	WSON	NGG	6	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	L256B	Samples
LP38691QSD-2.5/NOPB	ACTIVE	WSON	NGG	6	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	L257B	Samples
LP38691QSD-3.3/NOPB	ACTIVE	WSON	NGG	6	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	L258B	Samples
LP38691QSD-5.0/NOPB	ACTIVE	WSON	NGG	6	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	L259B	Samples
LP38691QSDX-1.8/NOPB	ACTIVE	WSON	NGG	6	4500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	L256B	Samples



28-Jan-2015

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
LP38691QSDX-2.5/NOPB	ACTIVE	WSON	NGG	6	4500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	L257B	Sample
LP38691QSDX-3.3/NOPB	ACTIVE	WSON	NGG	6	4500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	L258B	Sample
LP38691QSDX-5.0/NOPB	ACTIVE	WSON	NGG	6	4500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	L259B	Sample
LP38691SD-1.8	NRND	WSON	NGG	6	1000	TBD	Call TI	Call TI	-40 to 125	L118B	
LP38691SD-1.8/NOPB	ACTIVE	WSON	NGG	6	1000	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-40 to 125	L118B	Sample
LP38691SD-2.5/NOPB	ACTIVE	WSON	NGG	6	1000	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-40 to 125	L119B	Sample
LP38691SD-3.3/NOPB	ACTIVE	WSON	NGG	6	1000	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-40 to 125	L120B	Sample
LP38691SD-5.0/NOPB	ACTIVE	WSON	NGG	6	1000	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-40 to 125	L121B	Sample
LP38691SDX-1.8/NOPB	ACTIVE	WSON	NGG	6	4500	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-40 to 125	L118B	Sample
LP38691SDX-2.5/NOPB	ACTIVE	WSON	NGG	6	4500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	L119B	Sample
LP38691SDX-3.3/NOPB	ACTIVE	WSON	NGG	6	4500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	L120B	Sample
LP38691SDX-5.0/NOPB	ACTIVE	WSON	NGG	6	4500	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-40 to 125	L121B	Sample
LP38693MP-1.8/NOPB	ACTIVE	SOT-223	NDC	5	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	LJVB	Sample
LP38693MP-2.5/NOPB	ACTIVE	SOT-223	NDC	5	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	LJXB	Sample
LP38693MP-3.3	NRND	SOT-223	NDC	5	1000	TBD	Call TI	Call TI	-40 to 125	LJYB	
LP38693MP-3.3/NOPB	ACTIVE	SOT-223	NDC	5	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	LJYB	Sample
LP38693MP-5.0/NOPB	ACTIVE	SOT-223	NDC	5	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	LJZB	Sample
LP38693MPX-1.8/NOPB	ACTIVE	SOT-223	NDC	5	2000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	LJVB	Sample
LP38693MPX-2.5/NOPB	ACTIVE	SOT-223	NDC	5	2000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	LJXB	Sample





www.ti.com

28-Jan-2015

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
LP38693MPX-3.3/NOPB	ACTIVE	SOT-223	NDC	5	2000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	LJYB	Samples
LP38693MPX-5.0/NOPB	ACTIVE	SOT-223	NDC	5	2000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	LJZB	Samples
LP38693QSD-1.8/NOPB	ACTIVE	WSON	NGG	6	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	L260B	Samples
LP38693QSD-2.5/NOPB	ACTIVE	WSON	NGG	6	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	L261B	Samples
LP38693QSD-3.3/NOPB	ACTIVE	WSON	NGG	6	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	L262B	Samples
LP38693QSD-5.0/NOPB	ACTIVE	WSON	NGG	6	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	L263B	Samples
LP38693QSDX-1.8/NOPB	ACTIVE	WSON	NGG	6	4500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	L260B	Samples
LP38693QSDX-2.5/NOPB	ACTIVE	WSON	NGG	6	4500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	L261B	Samples
LP38693QSDX-3.3/NOPB	ACTIVE	WSON	NGG	6	4500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	L262B	Samples
LP38693QSDX-5.0/NOPB	ACTIVE	WSON	NGG	6	4500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	L263B	Samples
LP38693SD-1.8	NRND	WSON	NGG	6	1000	TBD	Call TI	Call TI	-40 to 125	L128B	
LP38693SD-1.8/NOPB	ACTIVE	WSON	NGG	6	1000	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-40 to 125	L128B	Samples
LP38693SD-2.5/NOPB	ACTIVE	WSON	NGG	6	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	L129B	Samples
LP38693SD-3.3	NRND	WSON	NGG	6	1000	TBD	Call TI	Call TI	-40 to 125	L130B	
LP38693SD-3.3/NOPB	ACTIVE	WSON	NGG	6	1000	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-40 to 125	L130B	Samples
LP38693SD-5.0	NRND	WSON	NGG	6	1000	TBD	Call TI	Call TI	-40 to 125	L131B	
LP38693SD-5.0/NOPB	ACTIVE	WSON	NGG	6	1000	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-40 to 125	L131B	Samples
LP38693SDX-1.8/NOPB	ACTIVE	WSON	NGG	6	4500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	L128B	Samples
LP38693SDX-2.5/NOPB	ACTIVE	WSON	NGG	6	4500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	L129B	Samples



PACKAGE OPTION ADDENDUM

28-Jan-2015

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
LP38693SDX-3.3/NOPB	ACTIVE	WSON	NGG	6	4500	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-40 to 125	L130B	Samples
LP38693SDX-5.0/NOPB	ACTIVE	WSON	NGG	6	4500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	L131B	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.





28-Jan-2015

OTHER QUALIFIED VERSIONS OF LP38691, LP38691-Q1, LP38693, LP38693-Q1:

• Catalog: LP38691, LP38693

• Automotive: LP38691-Q1, LP38693-Q1

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects

PACKAGE MATERIALS INFORMATION

www.ti.com 28-Jan-2015

TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LP38691DTX-1.8/NOPB	TO-252	NDP	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
LP38691DTX-2.5/NOPB	TO-252	NDP	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
LP38691DTX-3.3	TO-252	NDP	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
LP38691DTX-3.3/NOPB	TO-252	NDP	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
LP38691DTX-5.0/NOPB	TO-252	NDP	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
LP38691QSD-1.8/NOPB	WSON	NGG	6	1000	178.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38691QSD-2.5/NOPB	WSON	NGG	6	1000	178.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38691QSD-3.3/NOPB	WSON	NGG	6	1000	178.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38691QSD-5.0/NOPB	WSON	NGG	6	1000	178.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38691QSDX-1.8/NOPB	WSON	NGG	6	4500	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38691QSDX-2.5/NOPB	WSON	NGG	6	4500	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38691QSDX-3.3/NOPB	WSON	NGG	6	4500	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38691QSDX-5.0/NOPB	WSON	NGG	6	4500	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38691SD-1.8	WSON	NGG	6	1000	178.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38691SD-1.8/NOPB	WSON	NGG	6	1000	180.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38691SD-2.5/NOPB	WSON	NGG	6	1000	180.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38691SD-3.3/NOPB	WSON	NGG	6	1000	180.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38691SD-5.0/NOPB	WSON	NGG	6	1000	180.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1



PACKAGE MATERIALS INFORMATION

www.ti.com 28-Jan-2015

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LP38691SDX-1.8/NOPB	WSON	NGG	6	4500	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38691SDX-2.5/NOPB	WSON	NGG	6	4500	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38691SDX-3.3/NOPB	WSON	NGG	6	4500	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38691SDX-5.0/NOPB	WSON	NGG	6	4500	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38693MP-1.8/NOPB	SOT-223	NDC	5	1000	330.0	16.4	7.0	7.5	2.2	12.0	16.0	Q3
LP38693MP-2.5/NOPB	SOT-223	NDC	5	1000	330.0	16.4	7.0	7.5	2.2	12.0	16.0	Q3
LP38693MP-3.3	SOT-223	NDC	5	1000	330.0	16.4	7.0	7.5	2.2	12.0	16.0	Q3
LP38693MP-3.3/NOPB	SOT-223	NDC	5	1000	330.0	16.4	7.0	7.5	2.2	12.0	16.0	Q3
LP38693MP-5.0/NOPB	SOT-223	NDC	5	1000	330.0	16.4	7.0	7.5	2.2	12.0	16.0	Q3
LP38693MPX-1.8/NOPB	SOT-223	NDC	5	2000	330.0	16.4	7.0	7.5	2.2	12.0	16.0	Q3
LP38693MPX-2.5/NOPB	SOT-223	NDC	5	2000	330.0	16.4	7.0	7.5	2.2	12.0	16.0	Q3
LP38693MPX-3.3/NOPB	SOT-223	NDC	5	2000	330.0	16.4	7.0	7.5	2.2	12.0	16.0	Q3
LP38693MPX-5.0/NOPB	SOT-223	NDC	5	2000	330.0	16.4	7.0	7.5	2.2	12.0	16.0	Q3
LP38693QSD-1.8/NOPB	WSON	NGG	6	1000	178.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38693QSD-2.5/NOPB	WSON	NGG	6	1000	178.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38693QSD-3.3/NOPB	WSON	NGG	6	1000	178.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38693QSD-5.0/NOPB	WSON	NGG	6	1000	178.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38693QSDX-1.8/NOPB	WSON	NGG	6	4500	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38693QSDX-2.5/NOPB	WSON	NGG	6	4500	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38693QSDX-3.3/NOPB	WSON	NGG	6	4500	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38693QSDX-5.0/NOPB	WSON	NGG	6	4500	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38693SD-1.8	WSON	NGG	6	1000	178.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38693SD-1.8/NOPB	WSON	NGG	6	1000	180.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38693SD-2.5/NOPB	WSON	NGG	6	1000	178.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38693SD-3.3	WSON	NGG	6	1000	178.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38693SD-3.3/NOPB	WSON	NGG	6	1000	180.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38693SD-5.0	WSON	NGG	6	1000	178.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38693SD-5.0/NOPB	WSON	NGG	6	1000	180.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38693SDX-1.8/NOPB	WSON	NGG	6	4500	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38693SDX-2.5/NOPB	WSON	NGG	6	4500	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38693SDX-3.3/NOPB	WSON	NGG	6	4500	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LP38693SDX-5.0/NOPB	WSON	NGG	6	4500	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1

www.ti.com 28-Jan-2015



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LP38691DTX-1.8/NOPB	TO-252	NDP	3	2500	367.0	367.0	38.0
LP38691DTX-2.5/NOPB	TO-252	NDP	3	2500	367.0	367.0	38.0
LP38691DTX-3.3	TO-252	NDP	3	2500	367.0	367.0	35.0
LP38691DTX-3.3/NOPB	TO-252	NDP	3	2500	367.0	367.0	38.0
LP38691DTX-5.0/NOPB	TO-252	NDP	3	2500	367.0	367.0	38.0
LP38691QSD-1.8/NOPB	WSON	NGG	6	1000	210.0	185.0	35.0
LP38691QSD-2.5/NOPB	WSON	NGG	6	1000	210.0	185.0	35.0
LP38691QSD-3.3/NOPB	WSON	NGG	6	1000	210.0	185.0	35.0
LP38691QSD-5.0/NOPB	WSON	NGG	6	1000	210.0	185.0	35.0
LP38691QSDX-1.8/NOPB	WSON	NGG	6	4500	367.0	367.0	35.0
LP38691QSDX-2.5/NOPB	WSON	NGG	6	4500	367.0	367.0	35.0
LP38691QSDX-3.3/NOPB	WSON	NGG	6	4500	367.0	367.0	35.0
LP38691QSDX-5.0/NOPB	WSON	NGG	6	4500	367.0	367.0	35.0
LP38691SD-1.8	WSON	NGG	6	1000	210.0	185.0	35.0
LP38691SD-1.8/NOPB	WSON	NGG	6	1000	203.0	203.0	35.0
LP38691SD-2.5/NOPB	WSON	NGG	6	1000	203.0	203.0	35.0
LP38691SD-3.3/NOPB	WSON	NGG	6	1000	203.0	203.0	35.0
LP38691SD-5.0/NOPB	WSON	NGG	6	1000	203.0	203.0	35.0
LP38691SDX-1.8/NOPB	WSON	NGG	6	4500	346.0	346.0	35.0
LP38691SDX-2.5/NOPB	WSON	NGG	6	4500	367.0	367.0	35.0



PACKAGE MATERIALS INFORMATION

www.ti.com 28-Jan-2015

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LP38691SDX-3.3/NOPB	WSON	NGG	6	4500	367.0	367.0	35.0
LP38691SDX-5.0/NOPB	WSON	NGG	6	4500	346.0	346.0	35.0
LP38693MP-1.8/NOPB	SOT-223	NDC	5	1000	367.0	367.0	35.0
LP38693MP-2.5/NOPB	SOT-223	NDC	5	1000	367.0	367.0	35.0
LP38693MP-3.3	SOT-223	NDC	5	1000	367.0	367.0	35.0
LP38693MP-3.3/NOPB	SOT-223	NDC	5	1000	367.0	367.0	35.0
LP38693MP-5.0/NOPB	SOT-223	NDC	5	1000	367.0	367.0	35.0
LP38693MPX-1.8/NOPB	SOT-223	NDC	5	2000	367.0	367.0	35.0
LP38693MPX-2.5/NOPB	SOT-223	NDC	5	2000	367.0	367.0	35.0
LP38693MPX-3.3/NOPB	SOT-223	NDC	5	2000	367.0	367.0	35.0
LP38693MPX-5.0/NOPB	SOT-223	NDC	5	2000	367.0	367.0	35.0
LP38693QSD-1.8/NOPB	WSON	NGG	6	1000	210.0	185.0	35.0
LP38693QSD-2.5/NOPB	WSON	NGG	6	1000	210.0	185.0	35.0
LP38693QSD-3.3/NOPB	WSON	NGG	6	1000	210.0	185.0	35.0
LP38693QSD-5.0/NOPB	WSON	NGG	6	1000	210.0	185.0	35.0
LP38693QSDX-1.8/NOPB	WSON	NGG	6	4500	367.0	367.0	35.0
LP38693QSDX-2.5/NOPB	WSON	NGG	6	4500	367.0	367.0	35.0
LP38693QSDX-3.3/NOPB	WSON	NGG	6	4500	367.0	367.0	35.0
LP38693QSDX-5.0/NOPB	WSON	NGG	6	4500	367.0	367.0	35.0
LP38693SD-1.8	WSON	NGG	6	1000	210.0	185.0	35.0
LP38693SD-1.8/NOPB	WSON	NGG	6	1000	203.0	203.0	35.0
LP38693SD-2.5/NOPB	WSON	NGG	6	1000	210.0	185.0	35.0
LP38693SD-3.3	WSON	NGG	6	1000	210.0	185.0	35.0
LP38693SD-3.3/NOPB	WSON	NGG	6	1000	203.0	203.0	35.0
LP38693SD-5.0	WSON	NGG	6	1000	210.0	185.0	35.0
LP38693SD-5.0/NOPB	WSON	NGG	6	1000	203.0	203.0	35.0
LP38693SDX-1.8/NOPB	WSON	NGG	6	4500	367.0	367.0	35.0
LP38693SDX-2.5/NOPB	WSON	NGG	6	4500	367.0	367.0	35.0
LP38693SDX-3.3/NOPB	WSON	NGG	6	4500	346.0	346.0	35.0
LP38693SDX-5.0/NOPB	WSON	NGG	6	4500	367.0	367.0	35.0







IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products Applications

Audio www.ti.com/audio Automotive and Transportation www.ti.com/automotive **Amplifiers** amplifier.ti.com Communications and Telecom www.ti.com/communications **Data Converters** dataconverter.ti.com Computers and Peripherals www.ti.com/computers **DLP® Products** www.dlp.com Consumer Electronics www.ti.com/consumer-apps DSP dsp.ti.com **Energy and Lighting** www.ti.com/energy Clocks and Timers www.ti.com/clocks Industrial www.ti.com/industrial Interface interface.ti.com Medical www.ti.com/medical Logic Security www.ti.com/security logic.ti.com

Power Mgmt power.ti.com Space, Avionics and Defense www.ti.com/space-avionics-defense

Microcontrollers microcontroller.ti.com Video and Imaging www.ti.com/video

RFID www.ti-rfid.com

OMAP Applications Processors www.ti.com/omap TI E2E Community e2e.ti.com

Wireless Connectivity www.ti.com/wirelessconnectivity